



RoHS

MS5525DSO (Digital Small Outline)

SPECIFICATIONS

- Integrated Digital Pressure Sensor (24-bit ΔΣ ADC)
- Fast Conversion Down to 1 ms
- Low Power, 1 μA (standby < 0.15 μA)
- Supply Voltage: 1.8 to 3.6V
- Pressure Range: 1 to 30 PSI
- I²C and SPI Interface

The MS5525DSO is a new generation of Digital Small Outline pressure sensors from MEAS with SPI and I²C bus interface designed for high volume OEM users. The sensor module includes a pressure sensor and an ultra low power 24-bit $\Delta\Sigma$ ADC with internal factory calibrated coefficients. It provides a 24-bit digital pressure and temperature value and different operation modes that allow the user to optimize for conversion speed and current consumption. The MS5525DSO can be interfaced to virtually any microcontroller. The communication protocol is simple, without the need of programming internal registers in the device.

This new sensor module generation is based on leading MEMS technology and latest benefits from TE proven experience and know-how in high volume manufacturing of pressure modules, which have been widely used for over a decade.

The rugged engineered thermoplastic transducer is available in single and dual port configurations, and can measure absolute, gauge, compound, and differential pressure from 1 to 30psi.

FEATURES

- Small Outline IC Package
- Barbed Pressure Ports
- Low Power, High Resolution ADC
- Digital Pressure and Temperature Outputs

APPLICATIONS

- Factory Automation
- Altitude and Airspeed Measurements
- Medical Instruments
- Leak Detection

STANDARD RANGES (PSI)

| FS Pressure | Absolute | Gauge | Differential |
|-------------|-----------|-------------------|---------------|
| 1 | | DB, SB, ST, DH,FT | DB, SB,ST, DH |
| 2 | | DB, SB, ST, DH,FT | DB, SB,ST, DH |
| 5 | | DB, SB, ST, DH,FT | DB, SB,ST ,DH |
| 15 | DB, DH,FT | DB, SB, ST, DH,FT | DB, DH |
| 30 | DB, DH,FT | DB, SB, ST, DH,FT | DB, DH |

See Package Configurations: DB= Dual Barb, DH= Dual Hole, SB=Single Barb, ST=Single Tube, FT=Front Side Tube

ABSOLUTE MAXIMUM RATING

| Parameter | Conditions | Min | Max | Unit | Symbol/Notes | |
|---------------------|-------------------------------------|-------------------|-----|------|-----------------|--|
| Supply Voltage | $T_A = 25^{\circ}C$ | -0.3 | 3.6 | V | V _{DD} | |
| Storage Temperature | | -40 | 125 | °C | | |
| Overpressure | $T_A = 25 \ ^{\circ}C$, both Ports | | 60 | psi | | |
| Burst Pressure | T _A = 25 °C, Port 1 | | | psi | See Table 1 | |
| ESD | НВМ | -4 | +4 | kV | EN 61000-4-2 | |
| Solder Temperature | | 250°C, 5 sec max. | | | | |

Table 1- BURST PRESSURE BY RANGE AND PORT DESIGNATION.

| Range | Port 1 | Port 2 | Unit |
|-------|--------|--------|------|
| 001 | 10 | 10 | psi |
| 002 | 20 | 20 | psi |
| 005 | 50 | 15 | psi |
| 015 | 120 | 60 | psi |
| 030 | 120 | 120 | psi |

ENVIRONMENTAL SPECIFICATIONS

| Parameter | Conditions |
|----------------------|---|
| Mechanical Shock | Mil Spec 202F, Method 213B, Condition C, 3 Drops |
| Mechanical Vibration | Mil Spec 202F, Method 214A, Condition 1E, 1Hr Each Axis |
| Thermal Shock | 100 Cycles over Storage Temperature, 30 minute dwell |
| Life | 1 Million FS Cycles |
| MTTF | >10Yrs, 70 °C, 1 Million Pressure Cycles, 120%FS Pressure |

PERFORMANCE SPECIFICATIONS

Supply Voltage¹ 3.0 Vdc

Reference Temperature: 25°C (unless otherwise specified)

| PARAMETERS | MIN | TYP | MAX | UNITS | NOTES |
|--|---------------|-------------------|-------------------|------------------|-------|
| Operating Voltage | 1.8 | | 3.6 | | |
| ADC | | | 24 | bits | |
| Pressure Accuracy | : | See Table 2 Below | | %FS | 2,5 |
| Total Error Band (TEB) | -2.5 | | 2.5 | %FS | 3 |
| Temperature Accuracy (Reference Temperature) | | ±1.5 | | °C | 4,5 |
| Temperature Accuracy | | ±2.5 | | ٥C | 4,5 |
| Supply Current | Se | e OSR Table Belo | w | mA | |
| Compensated Temperature | 0 | | 85 | ٥C | |
| Operating Temperature | -40 | | +125 | ٥C | |
| Conversion Time | Se | e OSR Table Belo | w | mS | |
| Weight | | 3 | | grams | |
| Media | Non-Corrosive | Dry Gases Compati | ble with Silicon, | Glass, LCP, RTV, | |

Non-Corrosive Dry Gases Compatible with Silicon, Glass, LCP, RTV, Gold, Thermo-Epoxy, Silicone Gel, Aluminum and Epoxy. See "Wetted Material by Port Designation" chart.

Notes

- 1. Proper operation requires an external capacitor placed as shown in Application Circuit. Output is not ratiometric to supply voltage.
- 2. The maximum deviation from a best fit straight line(BFSL) fitted to the output measured over the pressure range at 25°C. Includes all errors due to pressure non linearity, hysteresis, and non repeatability.

 The maximum deviation from ideal output with respect to input pressure and temperature over the compensated temperature range. Total error band (TEB) includes all accuracy errors, thermal errors over the compensated temperature range, span and offset calibration tolerances. TEB values are valid only at the calibrated supply voltage.

- 4. The deviation from a best fit straight line (BFSL) from 25°C. to 85°C.
- 5. Six coefficients must be read by microcontroller software and are used in a mathematical calculation for converting D1 and D2 into compensated pressure and temperature values.

Table 2- TYPICAL ACCURACY SPECIFICATION BY PRESSURE RANGE

| Range | Port 1 | Port 2 | Unit |
|-------|--------|--------|------|
| 001 | ±0.25 | ±1.0 | %FSS |
| 002 | ±0.25 | ±0.5 | %FSS |
| 005 | ±0.50 | ±1.0 | %FSS |
| 015 | ±0.25 | ±0.25 | %FSS |
| 030 | ±0.25 | ±0.25 | %FSS |

OVERSAMPLNG RATIO (OSR) PERFORMANCE CHARACTERISTICS

SUPPLY CURRENT CHARACTERISTICS

| Parameter | Symbol | Conditions | Min. | Тур. | Max | Unit |
|------------------------|-----------------|-------------------|------|------|------|------|
| | | OSR 4096 | ; | 12.5 | | |
| Supply surrent | | 2048 | | 6.3 | | |
| Supply current | I _{DD} | 1024 | | 3.2 | | μA |
| (1 sample per sec.) | | 512 | | 1.7 | | |
| | | 256 | i - | 0.9 | | |
| Peak supply current | | during conversion | | 1.4 | | mA |
| Standby supply current | | at 25℃ | | 0.02 | 0.14 | μA |

ANALOG DIGITAL CONVERTER (ADC)

| Parameter | Symbol | Conditions | | Min. | Тур. | Max | Unit |
|-----------------|----------------|------------|------|------|------|------|------|
| | | OSR | 4096 | 7.40 | 8.22 | 9.04 | |
| | | | 2048 | 3.72 | 4.13 | 4.54 | |
| Conversion time | t _c | | 1024 | 1.88 | 2.08 | 2.28 | ms |
| | | | 512 | 0.95 | 1.06 | 1.17 | |
| | | | 256 | 0.48 | 0.54 | 0.60 | |

INPUT/OUTPUT SPECIFICATIONS

DIGITAL INPUTS (CSB, I²C, DIN, SCLK)

| Parameter | Symbol | Conditions | Min. | Тур. | Max | Unit |
|-----------------------|--|--------------|---------------------|------|----------------------|------|
| Serial data clock | SCLK | SPI protocol | | | 20 | MHz |
| Serial data clock | SCL | I2C protocol | | | 400 | kHz |
| Input high voltage | VIH | Pins CSB | 80% V _{DD} | | 100% V _{DD} | V |
| Input low voltage | VIL | | 0% V _{DD} | | 20% V _{DD} | V |
| Input leakage current | I _{leak25℃} I _{leak85℃} | at 25℃ | | | 0.15 | μA |
| Input capacitance | CIN | | | | 6 | pF |

PRESSURE OUTPUTS (I²C, DOUT)

| Parameter | Symbol | Conditions | Min. | Тур. | Max | Unit |
|---------------------|-----------------|------------------------------|---------------------|------|----------------------|------|
| Output high voltage | V _{OH} | I _{source} = 0.6 mA | 80% V _{DD} | | 100% V _{DD} | V |
| Output low voltage | V _{OL} | I _{sink} = 0.6 mA | 0% V _{DD} | | $20\% V_{DD}$ | V |
| Load capacitance | C_{LOAD} | | | | 16 | pF |

FUNCTIONAL DESCRIPTION

BLOCK DIAGRAM

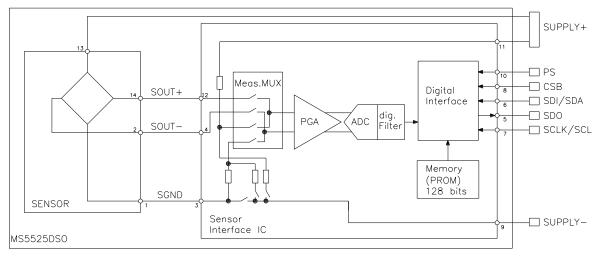


Figure 1: Block diagram of MS5525DSO

GENERAL

The MS5525DSO consists of a piezo-resistive sensor and a sensor interface IC. The main function of the MS5525DSO is to convert the uncompensated analog output voltage from the piezo-resistive pressure sensor to a 24-bit digital value, as well as providing a 24-bit digital value for the temperature of the sensor.

FACTORY CALIBRATION

Every module is individually factory calibrated at two temperatures and three pressures. As a result, six coefficients necessary to compensate for process variations and temperature variations are calculated and stored in the 128-bit PROM of each module. These bits, partitioned into six coefficients, C1 through C6, must be read by the microcontroller software and used in the program converting D1 and D2 into compensated pressure and temperature values.

The coefficients C0 and C7 are for factory calibration and CRC.

SERIAL INTERFACE

The MS5525DSO has built in two types of serial interfaces: SPI and I²C. Pulling the Protocol Select pin PS to low selects the SPI protocol, pulling PS to high activates the I²C bus protocol.

| Pin PS | Mode | Pins used |
|--------|------------------|---------------------|
| High | I ² C | SDA, SCL CSB |
| Low | SPI | SDI, SDO, SCLK, CSB |

SPI MODE

The external microcontroller clocks in the data through the input SCLK (Serial CLocK) and SDI (Serial Data In). In the SPI mode module can accept both mode 0 and mode 3 for the clock polarity and phase. The sensor responds on the output SDO (Serial Data Out). The pin CSB (Chip Select) is used to enable/disable the interface, so that other devices can talk on the same SPI bus. The CSB pin can be pulled high after the command is sent or after the end of the command execution (for example end of conversion). The best noise performance from the module is obtained when the SPI bus is idle and without communication to other devices during the ADC conversion.

I²C MODE & ADDRESSING

The external microcontroller clocks in the data through the input SCL (Serial CLock) and SDA (Serial DAta). The sensor responds on the same pin SDA which is bidirectional for the I²C bus interface. So this interface type uses only 2 signal lines and does not require a chip select, which can be favorable to reduce board space. In I²C -Mode the complement of the pin CSB (Chip Select) represents the LSB of the I²C address. It is possible to use two sensors with two different addresses on the I²C bus. The pin CSB must be connected to VDD or GND do not leave these pins unconnected.

| Pin CSB | Address (7 bits) |
|---------|------------------|
| High | 0x76 |
| Low | 0x77 |

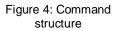
COMMANDS

The MS5525DSO has only five basic commands:

- 1. Reset
- 2. Read PROM (128 bit of calibration words)
- 3. D1 conversion
- 4. D2 conversion
- 5. Read ADC result (24 bit pressure / temperature)

Size of each command is 1 byte (8 bits) as described in the table below. After ADC read commands the device will return 24 bit result and after the PROM read 16bit result. The address of the PROM is embedded inside of the PROM read command using the Ad2, Ad1 and Ad0 bits.

| | Comr | nand I | oyte | | | | | | hex value |
|-----------------------|------|--------|------|-----|-------------|-------------|-------------|------|-----------|
| Bit number | 0 | 1 | 2 | 3 | 4 | 5 | 6 | 7 | |
| Bit name | PRM | COV | - | Тур | Ad2/ Os2 | Ad1/ Os1 | Ad0/ Os0 | Stop | |
| Command | | | | | | | | | |
| Reset | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 0x1E |
| Convert D1 (OSR=256) | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0x40 |
| Convert D1 (OSR=512) | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 0 | 0x42 |
| Convert D1 (OSR=1024) | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 0x44 |
| Convert D1 (OSR=2048) | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0x46 |
| Convert D1 (OSR=4096) | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 0x48 |
| Convert D2 (OSR=256) | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0x50 |
| Convert D2 (OSR=512) | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 0x52 |
| Convert D2 (OSR=1024) | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 0 | 0x54 |
| Convert D2 (OSR=2048) | 0 | 1 | 0 | 1 | 0 | 1 | 1 | 0 | 0x56 |
| Convert D2 (OSR=4096) | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0x58 |
| ADC Read | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0x00 |
| PROM Read | 1 | 0 | 1 | 0 | Ad2 | Ad1 | Ad0 | 0 | 0xA0 to |
| | | | | | | | | | 0xAE |



Start 5525DSO-pp005GS Example Tmin=-40°C , Tmax=125°C

| Variable Type[Bit]MinMaxC1Pressure Sensitivity, SENST1unsigned int 1616065535C2Pressure Offset, OFFT1unsigned int 1616065535C3Temperature Coefficient, Pressure Sensitivity, TCSunsigned int 1616065535C4Temperature Coefficient, Pressure Offset, TCOunsigned int 1616065535 | ariable | Coefficient Description | Recommended | Size [1] | Va | lue | Example/ | |
|---|---------|--|-----------------|----------|-----|-------|----------|--|
| C2 Pressure Offset, OFF _{T1} unsigned int 16 16 0 65535 C3 Temperature Coefficient, Pressure Sensitivity, TCS unsigned int 16 16 0 65535 C4 Temperature Coefficient, Pressure Offset, TCO unsigned int 16 16 0 65535 | allable | Coencient Description | Variable Type | [Bit] | Min | Max | Typical | |
| C2 Pressure Onset, OFFT1 Unsigned int 16 0 65535 C3 Temperature Coefficient, Pressure Sensitivity, TCS unsigned int 16 16 0 65535 C4 Temperature Coefficient, Pressure Offset, TCO unsigned int 16 16 0 65535 | C1 | Pressure Sensitivity, SENS _{T1} | unsigned int 16 | 16 | 0 | 65535 | 36402 | |
| C3 Temperature Coefficient, Pressure Sensitivity, TCS Unsigned int 16 16 0 65535 C4 Temperature Coefficient, Pressure Offset, TCO unsigned int 16 16 0 65535 | C2 | Pressure Offset, OFF _{T1} | unsigned int 16 | 16 | 0 | 65535 | 39473 | |
| C4 Temperature Coefficient, Pressure Offset, TCO unsigned int 16 0 65535 | C3 | Temperature Coefficient, Pressure Sensitivity, TCS | unsigned int 16 | 16 | 0 | 65535 | 40393 | |
| C5 Reference Temperature Test | C4 | Temperature Coefficient, Pressure Offset, TCO | unsigned int 16 | 16 | 0 | 65535 | 29523 | |
| | C5 | Reference Temperature, T _{REF} | unsigned int 16 | 16 | 0 | 65535 | 29854 | |
| C6 Temperature Coefficient Temperature, TEMPSENS unsigned int 16 ¹⁶ 0 65535 | C6 | Temperature Coefficient Temperature, TEMPSENS | unsigned int 16 | 16 | 0 | 65535 | 21917 | |

| | , |
|--|---|
| | |

| Read Digita | I Pressure and Temperature Data | | | | | |
|-------------|---------------------------------|-----------------|----|---|----------|---------|
| D1 | Digital Pressure Value | unsigned int 32 | 24 | 0 | 16777216 | 5240585 |
| D2 | Digital Temperature Value | unsigned int 32 | 24 | 0 | 16777216 | 3869265 |

| Calcul | ate Temperature | | | | | |
|--------|---|---------------|----|-----------|----------|-------------------------------|
| dT | Difference between actual and reference temperature dT = D2 - T_{RE F} = D2 - C5 * 2^{Q5} | signed int 32 | 25 | -16776960 | 16777216 | 47953 |
| TEMP | Measured temperature TEMP=20 °C+dT*TEMPSENS=2000+dT*C6/2 ^{Q6} | signed int 32 | 41 | -4000 | 12500 | 2501 =25.01 [°] C |

| Calculat | e Temperature Compensated Pressure | | | |
|----------|---|---------------|----|---------------------|
| OFF | Offset at actual temperature OFF=OFF _{T1} +TCO * dT=C2*2 ^{Q2} +(C4*dT)/2 ^{Q4} | signed int 64 | 41 | 5218046194 |
| SENS | Sensitivity at actual temperature SENS=SENS _{T1} +TCS*dT=C1* 2^{Q1} +(C3*dT)/ 2^{Q3} | signed int 64 | 41 | 2415906558 |
| Р | Temperature Compensated Pressure P=D1*SENS-OFF=(D1*SENS/2 ²¹ -OFF)/2 ¹⁵ | signed int 32 | 61 | 24996 =2.4996psi |

Display Pressure and Temperature Value

Figure 1: Flow chart for pressure and temperature reading and software compensation.

Qx Coefficients Matrix by Pressure Range

| Part Number | Pmin | Pmax | Q1 | Q2 | Q3 | Q4 | Q5 | Q6 | T _{RES} (°C) | P _{RES} (PSI) |
|------------------|------|------|----|----|----|----|----|----|--------------------------|---------------------------|
| | | | | | | | | | (0) | (1.31) |
| 5525DSO-pp001GS | 0 | 1 | 14 | 16 | 7 | 5 | 7 | 21 | 0.01 | 0.0001 |
| 5525DSO-pp001DS | -1 | 1 | 15 | 17 | 7 | 5 | 7 | 21 | 0.01 | 0.0001 |
| 5525DSO-pp002GS | 0 | 2 | 14 | 15 | 8 | 6 | 7 | 22 | 0.01 | 0.0001 |
| 5525DSO-pp002DS | -2 | 2 | 16 | 18 | 6 | 4 | 7 | 22 | 0.01 | 0.0001 |
| 5525DSO-pp005GS | 0 | 5 | 16 | 17 | 6 | 5 | 7 | 21 | 0.01 | 0.0001 |
| 5525DSO-pp005DS | -5 | 5 | 17 | 19 | 5 | 3 | 7 | 22 | 0.01 | 0.0001 |
| 5525DSO-pp0015AS | 0 | 15 | 16 | 17 | 6 | 5 | 7 | 22 | 0.01 | 0.0001 |
| 5525DSO-pp0015GS | 0 | 15 | 16 | 17 | 6 | 5 | 7 | 22 | 0.01 | 0.0001 |
| 5525DSO-pp0015DS | -15 | 15 | 17 | 19 | 5 | 3 | 7 | 22 | 0.01 | 0.0001 |
| 5525DSO-pp0030AS | 0 | 30 | 17 | 18 | 5 | 4 | 7 | 22 | 0.01 | 0.0001 |
| 5525DSO-pp0030GS | 0 | 30 | 17 | 18 | 5 | 4 | 7 | 22 | 0.01 | 0.0001 |
| 5525DSO-pp0030DS | -30 | 30 | 18 | 20 | 4 | 1 | 7 | 22 | 0.01 | 0.0001 |

MEMORY MAPPING

| Address | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---------|--------------------|--------------------|----|----|----|----|-------|---------|--------|---------|---|---|---|---|---|---|
| 0 | | | • | • | • | • | Reser | ved for | Manufa | acturer | | | | 8 | 8 | |
| 1 | | Coefficient 1 (C1) | | | | | | | | | | | | | | |
| 2 | | Coefficient 2 (C2) | | | | | | | | | | | | | | |
| 3 | Coefficient 3 (C3) | | | | | | | | | | | | | | | |
| 4 | Coefficient 4 (C4) | | | | | | | | | | | | | | | |
| 5 | Coefficient 5 (C5) | | | | | | | | | | | | | | | |
| 6 | Coefficient 6 (C6) | | | | | | | | | | | | | | | |
| 7 | CRC | | | | | | | | | | | | | | | |

Figure 2: Memory PROM Mapping

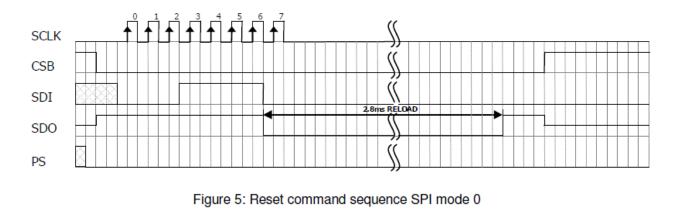
Notes

[1] Maximal size of intermediate result during evaluation of variable.

SPI INTERFACE

RESET SEQUENCE

The Reset sequence shall be sent once after power-on to make sure that the calibration PROM gets loaded into the internal register. It can be also used to reset the device ROM from an unknown condition



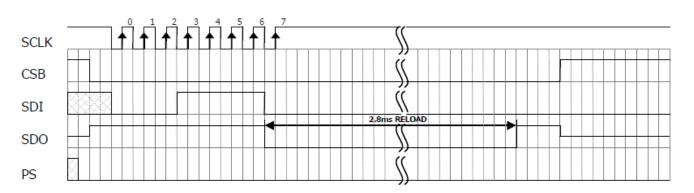


Figure 6: Reset command sequence SPI mode 3

CONVERSION SEQUENCE

The conversion command is used to initiate uncompensated pressure (D1) or uncompensated temperature (D2) conversion. The chip select can be disabled during this time to communicate with other devices.

After the conversion, using ADC read command the result is clocked out with the MSB first. If the conversion is not executed before the ADC read command, or the ADC read command is repeated, it will give 0 as the output result. If the ADC read command is sent during conversion the result will be 0, the conversion will not stop and the final result will be wrong. Conversion sequence sent during the already started conversion process will yield incorrect result as well.

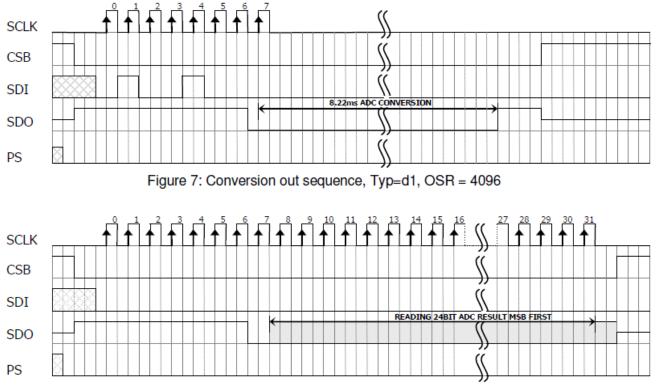
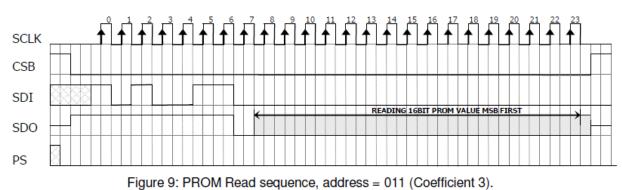


Figure 8: ADC Read sequence

PROM READ SEQUENCE

The read command for PROM shall be executed once after reset by the user to read the content of the calibration PROM and to calculate the calibration coefficients. There are in total 8 addresses resulting in a total memory of 128 bit. Address 0 contains factory data and the setup, addresses 1-6 calibration coefficients and address 7 contains the serial code and CRC. The command sequence is 8 bits long with a 16 bit result which is clocked with the MSB first.



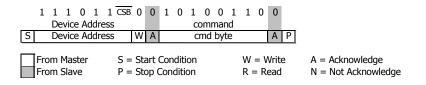
I²C INTERFACE

COMMANDS

Each I²C communication message starts with the start condition and it is ended with the stop condition. The MS5525DSO address is 111011Cx, where C is the complementary value of the pin CSB. Since the IC does not have a microcontroller inside, the commands for I²C and SPI are quite similar.

RESET SEQUENCE

The reset can be sent at any time. In the event that there is not a successful power on reset this may be caused by the SDA being blocked by the module in the acknowledge state. The only way to get the MS5525DSO to function is to send several SCLKs followed by a reset sequence or to repeat power on reset.





PROM READ SEQUENCE

The PROM Read command consists of two parts. First command sets up the system into PROM read mode. The second part gets the data from the system.

| 1 1 1 0 1 1 Device Address | | 1 0 1 0 0 1 command | 1 0 0 | |
|-------------------------------|-------------------------|------------------------|-----------------------|--|
| S Device Address | 6 W A | cmd byte | A P | |
| From Master From Slave | S = Start P = Stop (| | W = Write R = Read | A = Acknowledge N = Not Acknowledge |

Figure 11: I2C Command to read memory address= 011 (Coefficient 3)

| 1 1 1 0 1 1 CSB Device Address | 1 0 1 1 0 0 X data | X X X 0 X | X X X X X X X data | 0 |
|-----------------------------------|-----------------------------------|-----------------------|--|----|
| S Device Address | R A Memory bit 1 | 5-8 A | Memory bit 7 - 0 | ΝP |
| | Start Condition Stop Condition | W = Write R = Read | A = Acknowledge N = Not Acknowledge | ge |

Figure 12: I2C response from MS5525DSO

CONVERSION SEQUENCE

A conversion can be started by sending the command to MS5525DSO. When command is sent to the system it stays busy until conversion is done. When conversion is finished the data can be accessed by sending a Read command, when an acknowledge appears from the MS5525DSO, 24 SCLK cycles may be sent to receive all result bits. Every 8-bit the system waits for an acknowledge signal.

| 1 1 1 0 1 1 CSE Device Address | 3 0 0 0 1 0 0 1 0 command | 0 0 0 | |
|-----------------------------------|---------------------------------------|-----------------------|--|
| S Device Address | W A cmd byte | A P | |
| | = Start Condition = Stop Condition | W = Write R = Read | A = Acknowledge N = Not Acknowledge |

Figure 13: I²C Command to initiate a pressure conversion (OSR=4096, typ=D1)

| 1 1 1 0 1 1 CSB | 0 0 | 0 0 0 0 0 0 | 0 0 0 | |
|------------------|-----|------------------------|-----------------------|--|
| Device Address | | command | | |
| S Device Address | WA | cmd byte | AP | |
| | | Condition Condition | W = Write R = Read | A = Acknowledge N = Not Acknowledge |

Figure 14: I²C ADC read sequence

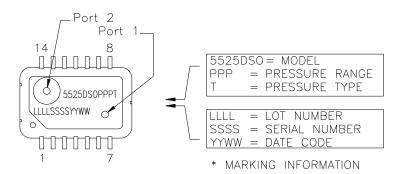
| 1 1 1 0 1 1 C Device Address | 310 | 0 X X X X X data | X X X 0 | 0 X X | X X X X X X data | 0 | X X X X X data | ххх | 0 |
|---------------------------------|-----|-----------------------------|---------------------|-------|--------------------------------------|----|----------------|-----|----|
| S Device Address | R A | A Data 23-1 | 6 A | 4 | Data 8 - 15 | Α | Data 7 - | 0 | ΝP |
| | | rt Condition p Condition | W = Wri R = Read | | A = Acknowledge N = Not Acknowled | ge | | | |

Figure 15: I²C response from MS5525DSO

CYCLIC REDUNDANCY CHECK (CRC)

MS5525DSO contains a PROM memory with 128-Bit. A 4-bit CRC has been implemented to check the data validity in memory. The application note AN520 describes in detail CRC-4 code used.

PINOUT, MARKING, AND PRESSURE TYPE CONFIGURATION



| Pressure Type | Pmin | Pmax | Description |
|--------------------------------|---------|---------|---|
| Absolute | 0psiA | +Prange | Output is proportional to the difference between 0psiA (Pmin) and pressure applied to Port 1. |
| Differential/ Bidirectional | -Prange | +Prange | Output is proportional to the difference between Port 1 and Port 2. Output swings positive when Port 2> Port 1. Output is 50% of total counts when Port 1=Port 2. |
| Gauge | 0psiG | +Prange | Output is proportional to the difference between 0psiG (Pmin) and Port 1. Output swings positive when Port 2> Port 1. |

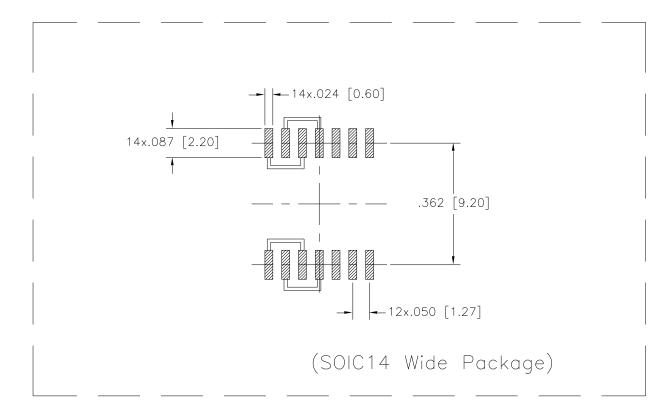
| Pin Name | Pin | Function | | | | |
|----------|-------|---|--------------------------|--|--|--|
| | | 12C | SPI | | | |
| SGND | 1,3 | Sensor Ground | | | | |
| SOUT- | 2,4 | Sensor Outputs, Negative | | | | |
| SDO | 5 | | Serial Data Output | | | |
| SDA/SDI | 6 | I ² C Data Input and Output | SPI Serial Data Input | | | |
| SCL/SCLK | 7 | I ² C Clock | SPI Clock | | | |
| CSB | 8 | Defines I ² C Address | Chip Select (Active Low) | | | |
| GND | 9 | Ground | | | | |
| PS | 10 | Protoco | I Select | | | |
| | | PS = (VDD) | PS = (GND) | | | |
| | | I ² C Protocol Selected | SPI Protocol Selected | | | |
| | | CSB= (VDD) I ² C Address =111011 | 10X (0xEC, 0xED) | | | |
| | | CSB= (GND) I ² C Address=1110111X (0xEE, 0xEF) | | | | |
| Supply+ | 11,13 | Positive Supply Voltage | | | | |
| SOUT+ | 12,14 | Sensor Outputs, Positive | | | | |

WETTED MATERIAL BY PORT DESIGNATION

| | Material | | | | | | | | |
|-------|---|---|---|---|---|---|---|---|--|
| Style | Port LCP Thermo-Epoxy Epoxy RTV Glass Silicon Silicone Style Resin Resin Glass Silicon Glass Glass Silicon Glass Glass Silicon Glass Glas Glas Glas | | | | | | | | |
| A 11 | Port 1 | Х | Х | Х | | | | Х | |
| All | Port 2 | Х | Х | Х | Х | Х | Х | | |

"X" Indicates Wetted Materials

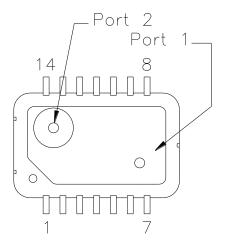
RECOMMEND PCB LAYOUT



| PAD NO. | FUNCTION | PAD NO. | FUNCTION |
|---------|----------|---------|----------|
| 1 | SGND | 8 | CSB |
| 2 | SOUT- | 9 | SUPPLY- |
| 3 | SGND | 10 | PS |
| 4 | SOUT- | 11 | SUPPLY+ |
| 5 | SDO | 12 | SOUT+ |
| 6 | SDI/SDA | 13 | SUPPLY+ |
| 7 | SCLK/SCL | 14 | SOUT+ |

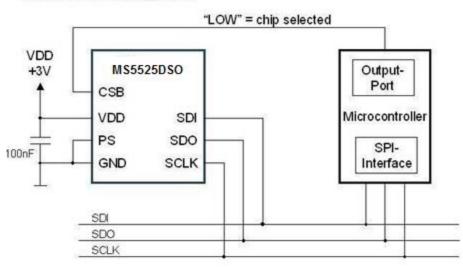
FUNCTION PINS THAT SHARE THE SAME NAME (SGND, SOUT+, SOUT-, SUPPLY+) MUST BE CONNECTED TOGETHER ON PCB FOR PROPER OPERATION.

NEED TO PLACE 0.1uF DECOUPING CAPACITOR BETWEEN SUPPLY+ AND SUPPLY- ON PCB AND AS CLOSE AS POSSIBLE TO SENSOR



APPLICATION CIRCUIT

The MS5525DSO is a circuit that can be used in conjunction with a microcontroller. It is designed for low-voltage systems with a supply voltage of 3 V.



SPI protocol communication

I²C protocol communication

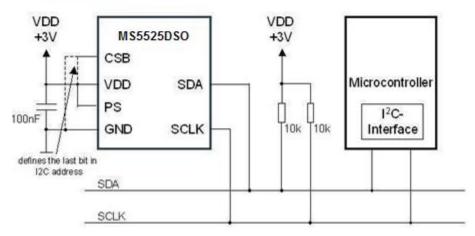


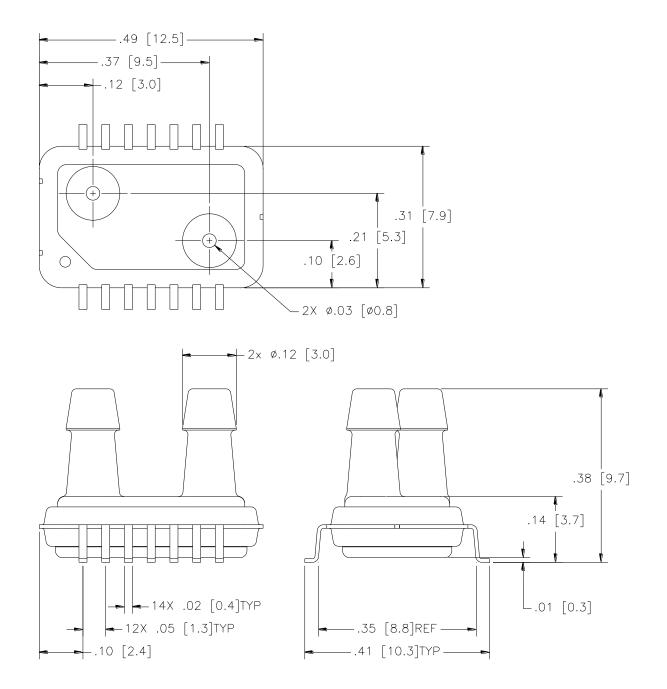
Figure 17: Typical application circuit with SPI / I²C protocol communication

Note

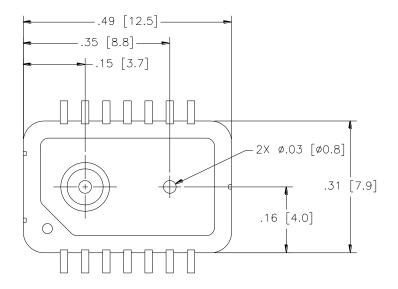
1. Place 100nF capacitor between Supply and GND to within 2 cm of sensor.

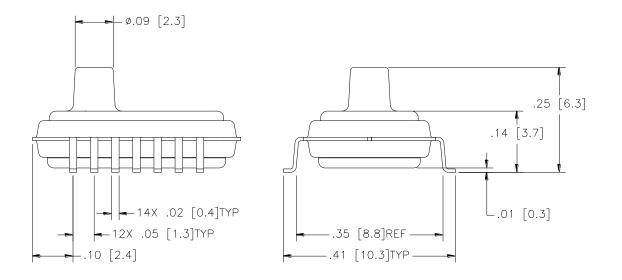
DIMENSIONS

MS5525DSO-DBxxxyS

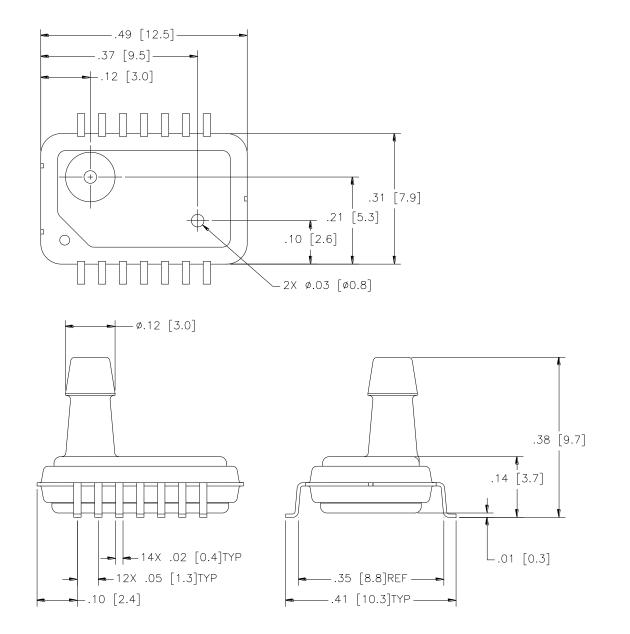


MS5525DSO-STxxxyS

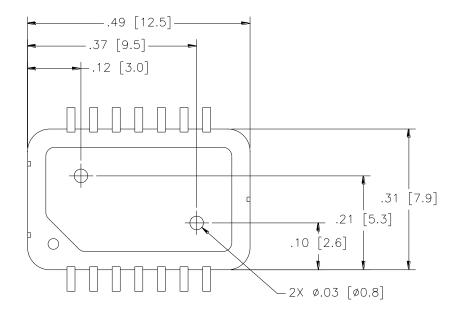


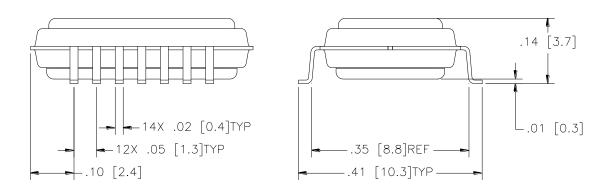


MS5525DSO-SBxxxyS

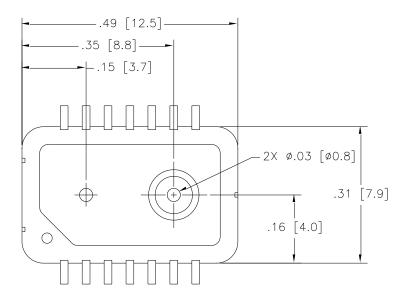


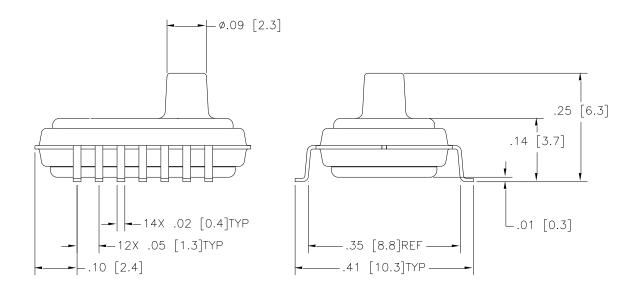
MS5525DSO-DHxxxyS





MS5525DSO-FTxxxyS





ORDERING INFORMATION

| 5525DSO | - | DB | 005 | G | S | |
|-----------|---|---|---------------------------------|---|---------------|--|
| Model | - | Package Style Range | | Pressure Type | Pin Style | |
| MS5525DSO | - | DB = Dual Barb SB = Single Barb ST = Single Tube DH = Dual Hole FT = Front Tube | 001 002 005 015 030 | A = AbsoluteD = DifferentialG = Gauge | S = Gull Wing | |

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